Vishay Semiconductors

High Performance Schottky Rectifier, 1 A

Anode

-0

SMB

1.0 A

100 V

0.78 V

1 mA at 125 °C

175 °C

Single die

1.0 mJ



- · Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912
- · Designed and gualified for industrial level

DESCRIPTION

The VS-10BQ100PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	A		
V _{RRM}		100	V		
I _{FSM}	t _p = 5 μs sine	780	A		
V _F	1.0 A _{pk} , T _J = 125 °C	0.62	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10BQ100PbF	UNITS	
Maximum DC reverse voltage	V _R	100	V	
Maximum working peak reverse voltage	V _{RWM}	100	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_L = 152 °C, rectangular waveform		1.0	А
Maximum peak one cycle non-repetitive surge current		I _{FSM} 5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated V _{RRM} applied		780	А
	IFSM		38		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 0.5 A, L = 8 mH		1.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.5	А

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SMB

PRODUCT SUMMARY

Package

I_{F(AV)}

 V_{R} V_F at I_F

 I_{RM}

T_J max.

Diode variation

E_{AS}



VS-10BQ100PbF



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1		1 A	T - 25 °C	0.78	
	V _{FM} ⁽¹⁾	2 A	T _J = 25 °C 0.89 0.62	0.89	v
	VFM (')	1 A		0.62	
		2 A	T _J = 125 °C	0.72	
Maximum reverse leakage current See fig. 2	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5 1	mA
	IRM (")	T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$		
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		42	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of charge	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to lead	R _{thJL} ⁽²⁾	DC operation	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		80	0/14
Approximate weight			0.10	g
			0.003	oz.
Marking device		Case style SMB (similar DO-214AA)	V	IJ

Notes

 $\frac{dP_{tot}}{T} < \frac{R_{thJA}}{R_{thJA}}$ (1) thermal runaway condition for a diode on its own heatsink

(2) Mounted 1" square PCB

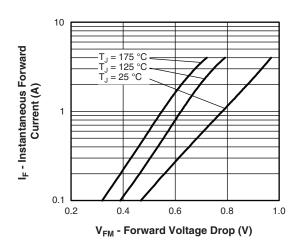


Fig. 1 - Maximum Forward Voltage Drop Characteristics

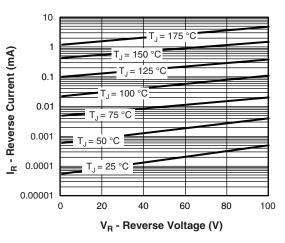


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

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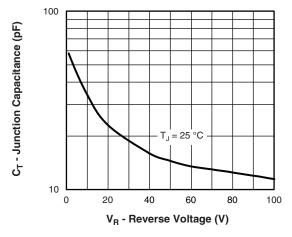


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

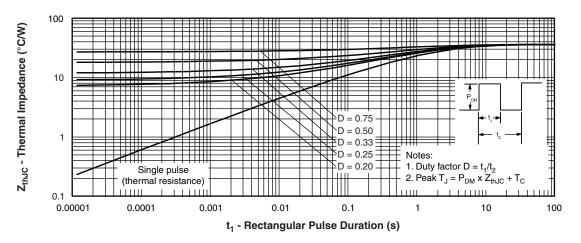
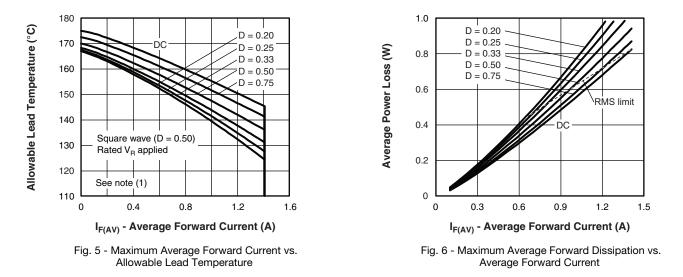


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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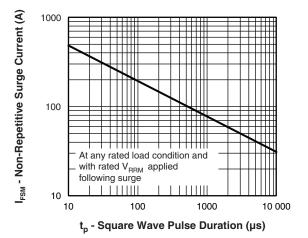
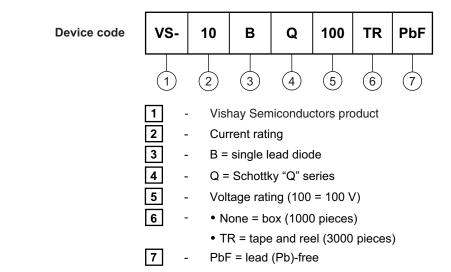


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

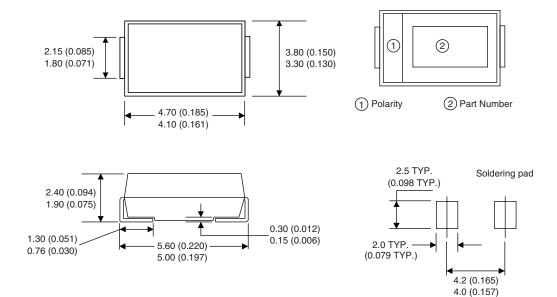


Outline Dimensions

Vishay High Power Products

SMB

DIMENSIONS in millimeters (inches)





Vishay

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